OKI Semiconductor

MSM9200-xx

This version: Nov. 1997 Previous version: Jul. 1996

5×7 Dot Character \times 16-Digit Display Controller/Driver with Character RAM

GENERAL DESCRIPTION

The MSM9200-xx is a dot matrix vacuum fluorescent display tube controller driver IC which displays characters, numerics and symbols.

Dot matrix vacuum fluorescent display tube drive signals are generated by serial data sent from a microcontroller. A display system is easily realized by internal ROM and RAM for character display.

The MSM9200-xx has low power consumption because it is munufactured in CMOS process technology.

-01 and -02 are available as general codes.

Custom codes are provided if necessary.

FEATURES

Logic power supply (V_{DD}) : 3.3 V±10%/5.0 V±10%
Fluorescent display tube drive power supply (V_{DISP}) : 3.3 V±10%/5.0 V±10%
Fluorescent display tube drive power supply (V_{FL}) :-20 to -60 V
VFD driver output current

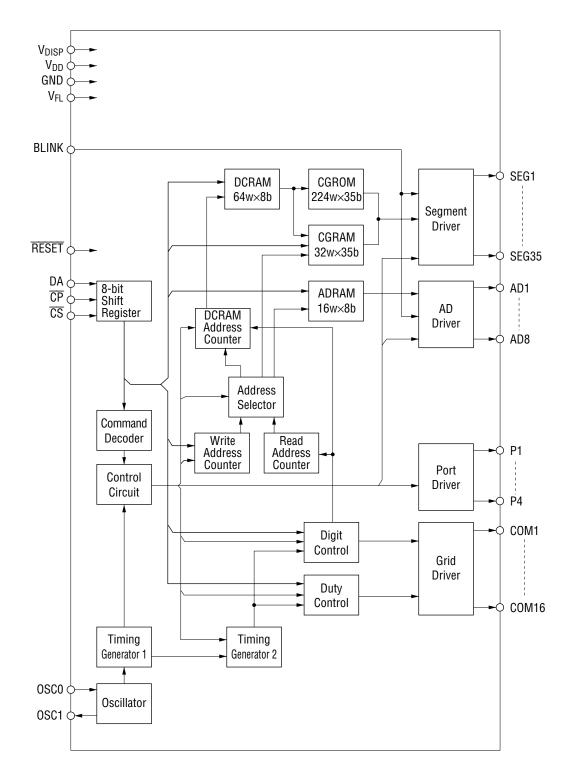
(VFD driver output can directly be connected to the fluorescent display tube. No pull-down resistor is required.)

10010101 10 100	[uncu.)				
- Segment dr	iver (SEG1 to SEG35) : -5 1	mA	$(V_{FL}=-60V)$	
- Segment dr	iver (AD1 to AD8)	:-10	mA	$(V_{FL}=-60V)$	
- Grid driver	(COM1 to COM16)	: -30	mA	$(V_{FL} = -60V)$	
General outp	ut port output curre	nt			
- Output driv			mA (V _{DD} =	=3.3V±10%)	
*		±2	mA (V _{DD} =	=5.0V±10%)	
• Content of di	splay		22		
	5×7 dots, 224 types	(cha	racter data	h)	
	5×7 dots, 32 types				
	16 (display digit) >				
				aracter data display)	
- General out	•	4 bits (stat		1 7	
• Display contr					
- Display dig		: 1 to	0 16 digits		
	y (contrast adjustme		0		
× ,	k position specificat		8		
× ,	ft (left and right)		: Can be set only for SEG output		
- All lights O	e				
6			: DA, \overline{CS} , \overline{CP} , and BLINK (5 interfaces when \overline{RESET} is		
		add			
• 1 byte instru specification)		cluding da	ata write f	to RAM and display blink position	
^	rcuit included (exter	mal C and I	२)		
Package:	can menurea (catel		••/		
i ucinage.					

80-pin plastic QFP (QFP80-P-1414-0.65-K)

(Product name: MSM9200-xxGS-K) xx indicated the code number.

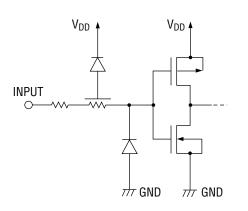
BLOCK DIAGRAM



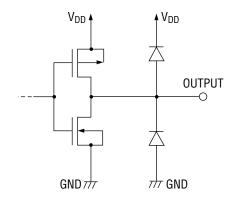
INPUT AND OUTPUT CONFIGURATION

Schematic Diagrams of Logic Portion Input and Output Circuits

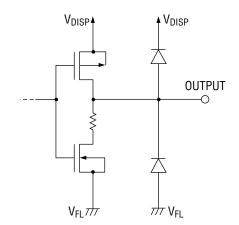
Input Pin



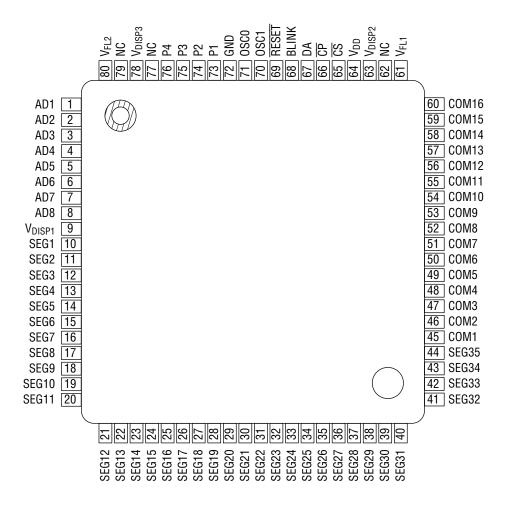
Output Pin



Schematic Diagram of Driver Output Circuit



PIN CONFIGURATION (TOP VIEW)



NC: No connection

80-Pin Plastic QFP

PIN DESCRIPTION

Pin	Symbol	Туре	Connects to:	Description
			Fluorescent	Fluorescent display tube anode electrode drive output.
10 to 44	SEG1-35	0	tube grid	Directly connected to fluorescent display tube and a pull-down
			electrode	resistor is not necessary. I _{0H} >–5 mA
			Fluorescent	Fluorescent display tube grid electrode drive output.
45 to 60	COM1-16	0	tube grid	Directly connected to fluorescent display tube and a pull-down
			electrode	resistor is not necessary. I _{OH} >-30 mA
			Fluorescent	Fluorescent display tube grid electrode drive output.
1 to 8	AD1-8	0	tube grid	Directly connected to fluorescent display tube and a pull-down
			electrode	resistor is not necessary. I _{OH} >-10 mA
			LED drive	General port output.
73 to 76	P1-4	0	control	Output of these pins in static mode, so control for LED driving is
			terminals	performed through these pins.
64	V _{DD}	—	Power	V _{DD} -GND are power supplies for internal logic.
9, 63, 78	V _{DISP1-3}		supply	$V_{\text{DISP}}\text{-}V_{\text{FL}}$ are power supplies for driving fluorescent tubes.
72	GND	_		Use the same power supply for V_{DD} and $V_{\text{DISP}}.$
61, 80	V _{FL1-2}	_		Apply V_{FL} after V_{DD} and V_{DISP} are applied.
67	DA		Micro-	Serial data input (positive logic).
07	DA		controller	Input from LSB.
66	CP		Micro-	Shift clock input.
00	01		controller	Serial data is shifted on the rising edge of \overline{CP} .
65	CS	1	Micro-	Chip select input.
00	00		controller	"H" disables serial data transfer.
				Display blink frequency input (square wave).
				Only the position specified by the display blink position set command
			Micro-	is validated.
68	BLINK	BLINK I		The time of "High" (light ON) and "Low" (light OFF) level of the signal
			controller	frequency to be input to BLINK is the blink time.
				Fix BLINK pin to the V_{DD} or GND pin when the display blink control
				is not used.

Pin	Symbol	Туре	Connects to:	Description
69	RESET	1	Micro- controller or C ₂ , R ₂	Reset input (pull-up resistor included)."Low" initializes all the functions.Initial status is as follows.• Address of each RAM• Data of each RAM• Display digit• Display digit• Content is undefined• Display digit• Contrast adjusment• O/16• Display blink• All lights ON or OFF• All outputs• All outputs• Concected externally)• Connected externally)• See Application Circuit.
71	OSCO	I		External RC pin for RC oscillation. Connect R and C externally. The RC time constant depends on the V _{DD} voltage used. Set the target oscillation frequency to 2 MHz.
70	OSC1	0	- C ₁ , R ₁	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

Parameter	Symbol	Condition	Rating	Unit
Supply Voltage 1	V _{DD}	(*1)	-0.3 to 6.5	V
Supply Voltage 1	V _{DISP}	(*1)	-0.3 to 6.5	V
Supply Voltage 2	V _{FL}	—	-80 to V _{DISP} +0.3	V
Input Voltage	V _{IN}	—	-80 to V _{DD} +0.3	V
Power Dissipation	PD	Ta≤25°C	565	mW
Storage Temperature	T _{STG}	—	–55 to 150	°C
	I ₀₁	COM1-COM16	-40 to 0.0	
Output Current	I ₀₂	AD1-AD8	-20 to 0.0	m 1
Output Current	I ₀₃	SEG1-SEG35	-10 to 0.0	— mA
	I ₀₄	P1-P4	-4.0 to 4.0	

ABSOLUTE MAXIMUM RATINGS

*1 Use the same power supply for V_{DD} and V_{DISP} .

RECOMMENDED OPERATING CONDITIONS-1

When the power supply voltage is 5V (typ).	When the	power supp	oly voltage	e is 5V (typ).
--	----------	------------	-------------	--------------	----

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage 1	V _{DD}	_	4.5	5.0	5.5	V
Supply Voltage 2	V _{DISP} V _{FL}		-60		-20	V
High Level Input Voltage	V _{IH}	All input pins excluding OSCO pin	0.7V _{DD}	_		V
Low Level Input Voltage	V _{IL}	All input pins excluding OSCO pin		_	0.3V _{DD}	V
CP Frequency	f _C	—	_	_	1.0	MHz
Oscillation Frequency	fosc	R ₁ =3.3kΩ, C ₁ =47pF	1.5	2.0	2.5	MHz
Frame Frequency	f _{FR}	DIGIT=1–16, R ₁ =3.3kΩ, C ₁ =47pF	183	244	305	Hz
RESET Input Time	t _{RSON}	R ₂ =1.0kΩ, C ₂ =0.1PF	0	_	200	μs
Operating Temperature	T _{OP}	—	-40		85	°C

RECOMMENDED OPERATING CONDITIONS-2

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Supply Voltage 1	V _{DD}		3.0	3.3	3.6	V
Supply Voltage 1	V _{DISP}	_	3.0	3.3	3.0	v
Supply Voltage 2	V _{FL}	—	-60		-20	V
High Level Input Voltage	VIH	All input pins excluding OSCO pin	0.8V _{DD}			V
Low Level Input Voltage	VIL	All input pins excluding OSCO pin	_		0.2V _{DD}	V
CP Frequency	f _C	—	_		1.0	MHz
Oscillation Frequency	f _{OSC}	R ₁ =3.3kΩ, C ₁ =39pF	1.5	2.0	2.5	MHz
Frame Frequency	f _{FR}	DIGIT=1-16, R ₁ =3.3kΩ, C ₁ =39pF	183	244	305	Hz
RESET Input Time	t _{RSON}	R ₂ =1.0kΩ, C ₂ =0.1µF	0		200	μs
Operating Temperature	T _{OP}	—	-40	_	85	°C

When the power supply voltage is 3.3V (typ).

ELECTRICAL CHARACTERISTICS

DC Characteristics-1

($V_{DD}=V_{DISP}=5.0V\pm10\%$, $V_{FL}=-60V$, Ta=-40 to +85°C, unless otherwise specified)

Parameter	Symbol	Applied pin		Condition	Min.	Max.	Unit
High Level Input Voltage	V _{IH}	$\overline{\text{CS}}, \overline{\text{CP}}, \text{BLINK},$			0.7V _{DD}		V
	• IN	DA, RESET			0.1 100		
Low Level Input Voltage	V _{IL}	CS, CP, BLINK,		_	_	0.3V _{DD}	V
	۷IL	DA, RESET				0.0100	v
High Level Input Current	I	CS, CP, BLINK,		V _{IH} =V _{DD}	-1.0	1.0	μA
	I _{IH}	DA, RESET		VIH-VDD	-1.0	1.0	μΛ
Low Level Input Current	I.,	$\overline{\text{CS}}, \overline{\text{CP}}, \text{BLINK},$		V _{IL} =0.0V	-1.0	1.0	
Low Level input Guilent	Ι _{ΙL}	DA, RESET		VIL=0.0V	-1.0	1.0	μA
	V _{OH1}	COM1-16	I _{0H1} =–30mA		V _{DISP} -1.5	—	V
High Level Output	V _{0H2}	AD1-8		I _{0H2} =–10mA	V _{DISP} -1.5	—	V
Voltage	V _{OH3}	SEG1-35	I _{OH3} =–5mA		V _{DISP} -1.5	—	V
	V _{OH4}	P1-4		I _{OH4} =-2mA	V _{DD} -1.0	—	V
		COM1-16					
Low Level Output	V _{OL1}	AD1-8		—	—	V _{FL} +1.0	V
Voltage		SEG1-35					
	V _{0L2}	P1-4		I _{0L1} =2mA	—	1.0	V
				Duty=15/16			
	I _{DD1}		faaa	Digit=1-16	—	4	mA
Ourset Consumption		W W	f _{OSC} = 2MHz	All output lights ON			
Current Consumption		V _{DD} , V _{DISP}		Duty=8/16			
	I _{DD2}		no load	Digit=1–9	_	3	mA
				All output lights OFF			

DC Characteristics-2

($V_{DD}=V_{DISP}=3.3V\pm10\%$, $V_{FL}=-60V$, Ta=-40 to +85°C, unless otherwise specified)

Parameter	Symbol	Applied pin		Condition	Min.	Max.	Unit
High Level Input Voltage	V _{IH}	CS, CP, BLINK, DA, RESET		_	0.8V _{DD}		V
Low Level Input Voltage	V _{IL}	CS, CP, BLINK, DA, RESET		_		0.2V _{DD}	V
High Level Input Current	I _{IH}	CS, CP, BLINK, DA, RESET		V _{IH} =V _{DD}	-1.0	1.0	μA
Low Level Input Current	I _{IL}	CS, CP, BLINK, DA, RESET		V _{IL} =0.0V	-1.0	1.0	μA
	V _{OH1}	COM1-16		_{0H1} =30mA	V _{DISP} -1.5		V
High Level Output	V _{OH2}	AD1-8		_{0H2} =–10mA	V _{DISP} -1.5	_	V
Voltage	V _{OH3}	SEG1-35	I _{0H3} =–5mA		V _{DISP} -1.5	—	V
	V _{0H4}	P1-4		I _{OH4} =–1mA	V _{DD} -1.0	—	V
Low Level Output Voltage	V _{0L1}	COM1-16 AD1-8 SEG1-35		_	_	V _{FL} +1.0	V
	V _{OL2}	P1-4		I _{0L1} =1mA	—	1.0	V
Current Concurrentian	I _{DD1}	N N	f _{OSC} = 2MHz	Duty=15/16 Digit=1–16 All output lights ON		3	mA
Current Consumption	I _{DD2}	- V _{DD} , V _{DISP}	no load	Duty=8/16 Digit=1–9 All output lights OFF		2	mA

AC Characteristics-1

(V_DD, V_DISP=5.0V \pm 10%, V_{FL}=-60V, Ta=-40 to +85°C, unless otherwise specified)

Parameter	Symbol	Cond	dition	Min.	Max.	Unit
CP Frequncy	f _C	-	_		1.0	MHz
CP Pulse Width	t _{CW}	-	_	300		ns
DA Setup Time	t _{DS}	-	_	300	—	ns
DA Hold Time	t _{DH}	-	_	300	—	ns
CS Setup Time	t _{CSS}	-	_	300		ns
CS Hold Time	t _{CSH}	R ₁ =3.3kΩ, C ₁ =47PF		16		μs
CS Wait Time	t _{CSW}			300		ns
Data Processing Time	t _{DOFF}	R ₁ =3.3kΩ, C ₁ =47PF		8		μs
RESET Pulse Width	t _{RSON}	When RESET sign	al is input externally	300	—	ns
Waite DA Time	t _{RSOFF}	-	_	300		μs
All Output Clow Data	t _R	0 100 - 5	t _R =20% to 80%		4.0	μs
All Output Slow Rate	t _F	C _I =100pF	t _F =80% to 20%	—	4.0	μs
V _{DD} Rise Time	t _{PRZ}	When mounted in the unit		_	100	μs
V _{DD} Off Time	t _{POF}	When mounted in	the unit, V _{DD} =0.0V	5.0		ms

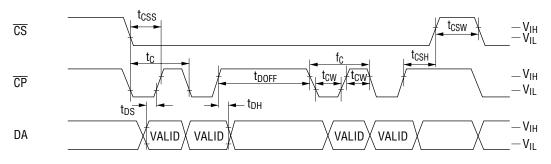
AC Characteristics-2

(V_DD, V_DISP=3.3V \pm 10%, V_{FL}=-60V, Ta=-40 to +85°C, unless otherwise specified)

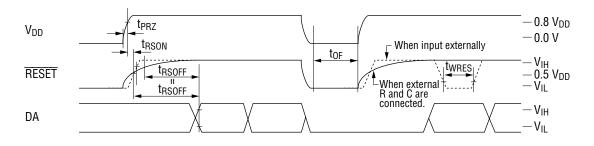
Parameter	Symbol	Cond	lition	Min.	Max.	Unit
CP Frequncy	f _C	-	_	_	1.0	MHz
CP Pulse Width	t _{CW}	-	_	300	—	ns
DA Setup Time	t _{DS}	-	_	300	—	ns
DA Hold Time	t _{DH}	-	_	300	—	ns
CS Setup Time	t _{CSS}	_		300	—	ns
CS Hold Time	t _{CSH}	$R_1=3.3k\Omega$, $C_1=39PF$		16	—	μs
CS Wait Time	t _{CSW}			300	—	ns
Data Processing Time	t _{DOFF}	R ₁ =3.3kΩ, C ₁ =39PF		8	—	μs
RESET Pulse Width	t _{WRES}	When RESET signal is input externally		300		ns
DA Wait Time	t _{RSOFF}	-	_	300		μs
All Output Claw Data	t _R	0 100pF	t _R =20% to 80%		4.0	μs
All Output Slew Rate	t _F	C _I =100pF	t _F =80% to 20%	—	4.0	μs
V _{DD} Rise Time	t _{PRZ}	When mounted in the unit		_	100	μs
V _{DD} Off Time	t _{POF}	When mounted in the unit, V _{DD} =0.0V		5.0	_	ms

TIMING DIAGRAM

• Data Timing



• Reset Timing



• Output Timing



Symbol	V _{DD} =3.3V±10%	V _{DD} =5.0V±10%
V _{IH}	0.8 V _{DD}	0.7 V _{DD}
VIL	0.2 V _{DD}	0.3 V _{DD}

FUNCTIONAL DESCRIPTION

Command List

	Command	LSB			1st	byte			MSB	LSB			2nd	byte			MSB	
	Commanu	B0	B1	B2	B3	B4	B5	B6	B7	B0	B1	B2	B3	B4	B5	B6	B7	
1	DCRAM data write 1	X0	X1	X2	Х3	1	0	0	0	CO	C1	C1 C2 C3 C4 C5 C6 C7						
2	DCRAM data write 2	X0	X1	X2	Х3	0	1	0	0	C0	C1 C2 C3 C4 C5 C6 C7							
3	DCRAM data write 3	X0	X1	X2	Х3	1	1	0	0	C0	C1	C2	C3	C4	C5	C6	C7	
4	DCRAM data write 4	X0	X1	X2	Х3	0	0	1	0	C0	C1	C2	C3	C4	C5	C6	C7	
										C0	C5	C10	C15	C20	C25	C30	*	2nd byte
										C1	C6	C11	C16	C21	C26	C31	*	3rd byte
5	CGRAM data write 1	X0	X1	X2	Х3	1	0	1	0	C2	C7	C12	C17	C22	C27	C32	*	4th byte
										C3	C8	C13	C18	C23	C28	C33	*	5th byte
										C4	C9	C14	C19	C24	C29	C34	*	6th byte
										C0	C5	C10	C15	C20	C25	C30	*	2nd byte
										C1	C6	C11	C16	C21	C26	C31	*	3rd byte
6	CGRAM data write 2	X0	X1	X2	X3	0	1	1	0	C2	C7	C12 C17		C22	C27	C32	*	4th byte
										C3	C8	C13	C18	C23	C28	C33	*	5th byte
										C4	C9	C14	C19	C24	C29	C34	*	6th byte
7	ADRAM data write	X0	X1	X2	Х3	1	1	1	0	CO	C1	C2	C3	C4	C5	C6	C7	
•	Display blink position	~~~	4.5	*	*	•	•	_		G1	G2	G3	G4	G5	G6	G7	G8	2nd byte
8	set	SG	AD		^	0	0	0	1	G9	G10	G11	G12	G13	G14	G15	G16	3rd byte
9	DCRAM address shift	S	*	*	*	1	0	0	1	*								-
А	DCRAM address reset	*	*	*	*	0	1	0	1	Xn		on't c		ificati	on fo	r aa ah	DAM	1
В	General output port set	P1	P2	P3	P4	1	1	0	1	Cn		: Address specification for each RAM : Character code specification for each RAM						
С	Display duty set	D0	D1	D2	D3	0	0	1	1	SG	-							
D	Number of digits set	K0	K1	K2	K3	1	0	1	1	AD : AD display area specification								
Е	All lights ON/OFF	L	Н	*	*	0	1	1	1	Gn		isplay		•				
	Test mode									S		eft and	•	•		•		
A / I= = =	n data is written to RAM			0004						Pn Dn		eneral isplay	•	•		•	CIIICa	11011

When data is written to RAM (DCRAM, CGRAM, ADRAM) continuously, addresses are internally incremented automatically.

Therefore it is not necessary to specify the 1st byte to write RAM data for the 2nd and later bytes.

Note: The test mode is used for inspection before shipment. It is not a user function. Kn : Number of digits specification

H : All lights ON instruction

L : All lights OFF instruction

	C0 AD1 C4 AD5	C1 AD2 C5 AD6	C2 AD3 C6 AD7	C3 AD4 C7 AD8	-	——— Area for the AD be output	RAM data to
	C0 SEG1 C5 SEG6 C10	C1 SEG2 C6 SEG7 C11	C2 SEG3 C7 SEG8 C12	C3 SEG4 C8 SEG9 C13	C4 SEG5 C9 SEG10 C14		
	SEG11 C15 SEG16 C20	SEG12 C16 SEG17 C21	SEG13 C17 SEG18 C22	SEG14 C18 SEG19 C23	SEG15 C19 SEG20 C24		
	SEG21 C25 SEG26 C30	SEG22 C26 SEG27 C31	SEG23 C27 SEG28 C32	SEG24 C28 SEG29 C33	SEG25 C29 SEG30 C34		
CGRAM written data. Corresponds to 2nd byte CGRAM written data. Corresponds to 3rd byte CGRAM written data. Corresponds to 4th byte	<u> SEG31</u>	SEG32	SEG33	SEG34	SEG35		Corresponds to 6th byte Corresponds to 5th byte

Data Transfer System and Command Write System

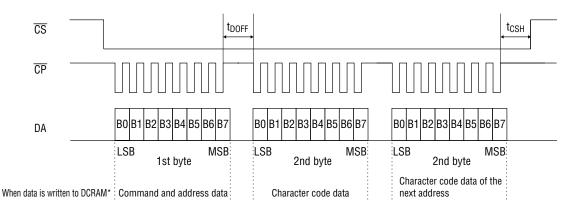
Display control command and data are written by an 8-bit serial transfer. Write timing is shown in the figure below.

Setting the $\overline{\text{CS}}$ pin to "Low" level enables a data transfer.

Data is 8 bits and is sequentially input into the DA pin from LSB (LSB first). As shown in the figure below, data is read by the shift register at the rising edge of the shift clock, which is input into the \overline{CP} pin. If 8-bit data is input, internal load signals are automatically generated and data is written to each register and RAM.

Therefore it is not necessary to input load signals from the outside.

Setting the \overline{CS} pin to "High" disables data transfer. Data input from the point when the \overline{CS} pin changes from "High" to "Low" is recognized in 8-bit units.



* When data is written to RAM (DCRAM, ADRAM, CGRAM) continuously, addresses are internally incremented automatically.

Therefore it is not necessary to specify the 1st byte to write RAM data for the 2nd and later bytes.

Reset Function

Reset is executed when the **RESET** pin is set to "L", (when turning power on, for example,) and initializes all functions.

Initial status is as follows.

- Address of each RAM address "00"H
- Data of each RAM All contents are undefined
- Display blink Blinking is disabled for all outputs
- General output port All general output ports go "Low"
- Display digit 16 digits
- Contrast adjustment 0/16
- All display lights ON or OFF OFF mode
- Segment output All segment outputs go "Low"
- AD output All AD outputs go "Low"

Reset again according to "Initial Setting Flowchart" after reset.

Description of Commands and Functions

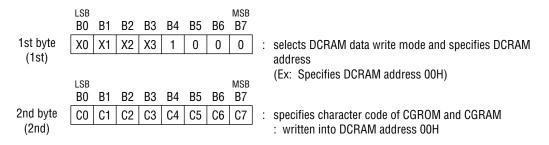
- 1. DCRAM data write 1 (Specifies the address (00H to 0FH) of DCRAM and writes the character code of CGROM and CGRAM.)
- 2. DCRAM data write 2 (Specifies the address (10H to 1FH) of DCRAM and writes the character code of CGROM and CGRAM.)
- 3. DCRAM data write 3 (Specifies the address (20H to 2FH) of DCRAM and writes the character code of CGROM and CGRAM.)
- 4. DCRAM data write 4 (Specifies the address (30H to 3FH) of DCRAM and writes the character code of CGROM and CGRAM.)

DCRAM (Data Control RAM) has a 6-bit address to store character code of CGROM and CGRAM. (4 bits can be set by the user and the 2 bits on the MSB side are automatically set.) The character code specified by DCRAM is converted to a 5×7 dot matrix character pattern via CGROM or CGRAM.

The capacity is 64×8 bits, which can store 64 characters.

Note: The addresses 00H to 3FH of DCRAM are automatically incremented.

[Command format]



To specify the character code of CGROM and CGRAM continuously to the next address, specify only character code as follows.

The addresses of DCRAM are automatically incremented. Specification of an address is unnecessary.

2nd byte (3rd)	LSB MSB B0 B1 B2 B3 B4 B5 B6 B7 C0 C1 C2 C3 C4 C5 C6 C7 LSB B0 B1 B2 B3 B4 B5 B6 B7	: specifies character code of CGROM and CGRAM : written into DCRAM address 01H
2nd byte (4th)	C0 C1 C2 C3 C4 C5 C6 C7	: specifies character code of CGROM and CGRAM : written into DCRAM address 02H
2nd byte (17th) 2nd byte (18th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C0 C1 C2 C3 C4 C5 C6 C7 LSB B0 B1 B2 B3 B4 B5 B6 B7 C0 C1 C2 C3 C4 C5 C6 C7 C0 C1 C2 C3 C4 C5 C6 C7	 specifies character code of CGROM and CGRAM written into DCRAM address 0FH specifies character code of CGROM and CGRAM written into DCRAM address 10H
2nd byte (65th) 2nd byte (66th)	LSB B2 B3 B4 B5 B6 B7 C0 C1 C2 C3 C4 C5 C6 C7 LSB B0 B1 B2 B3 B4 B5 B6 B7 LSB B0 B1 B2 C3 C4 C5 C6 C7 LSB C0 C1 C2 C3 C4 C5 C6 C7 LSB C0 C1 C2 C3 C4 C5 C6 C7	 specifies character code of CGROM and CGRAM written into DCRAM address 3FH specifies character code of CGROM and CGRAM DCRAM address 00H is rewritten

X0 (LSB) to X3 (MSB): DCRAM addresses (4 bits: 16 characters) Note: A total of 64 characters for the four specifications C0 (LSB) to C7 (MSB): Character code of CGROM and CGRAM (8 bits: 256 character)

[COM positions and set DCRAM addresses]

The states when $\overline{\text{RESET}}$ is input and DCRAM address reset commands are executed

Command No.	HEX	к0	К1	К2	КЗ	COM position	Command No.	HEX	к0	К1	К2	КЗ	COM position
	00	0	0	0	0	COM1		20	0	0	0	0	
	01	1	0	0	0	COM2		21	1	0	0	0	
1	 			 			3	 			 		
	0E	1	1	1	1	COM15		2E	1	1	1	1	
	0F	1	1	1	1	COM16		2F	1	1	1	1	
	10	0	0	0	0			30	0	0	0	0	
	11	1	0	0	0			31	1	0	0	0	
2	1			 			4	 			1		1
	1E	0	1	1	1			3E	0	1	1	1	
	1F	1	1	1	1			3F	1	1	1	1	

5. CGRAM data write 1

(Specifies the addresses 00H to 0FH of CGRAM and writes character pattern data.)

 CGRAM data write 2 (Specifies the addresses 10H to 1FH of CGRAM and writes character pattern data.)

CGRAM (Character Generator RAM) has a 5-bit address to store 5×7 dot matrix character patterns. (4 bits can be set by the user and the 1 bit on the MSB is automatically set.) A character pattern stored in CGRAM can be displayed by specifying the character code (address) by DCRAM. The address of CGRAM is assigned to 00H to 1FH. (All the other addresses are the CGROM addresses.)

Capacity is (16×2)×35×8 bits, which can store 32 types of character patterns.

Note: The addresses 00H to 1FH of CGRAM are automatically incremented.

[Command format]

LSB MSB B0 B1 B2 B3 Β4 B5 B6 Β7 1st byte X0 X1 X2 X3 1 0 1 0 selects CGRAM data write mode and specifies (1st) CGRAM address. (Ex: specifies CGRAM address 00H) MSB LSB B0 B1 B2 B3 Β4 Β5 B6 B7 2nd byte * C0 C5 C10 C15 C20 C25 C30 specifies 1st column data (2nd) : rewritten into CGRAM address 00H LSB MSB B5 B0 B1 B2 B3 Β4 B6 **B**7 3rd byte * C1 C6 C11 C16 C21 C26 C31 specifies 2nd column data (3rd) : rewritten into CGRAM address 00H LSB MSB B2 B3 B0 B1 Β4 B5 B6 Β7 4th byte * C7 C12 C17 C22 C27 C32 C2 specifies 3rd column data (4th) : rewritten into CGRAM address 00H LSB MSB B0 B1 B2 B3 Β4 B5 B6 **B**7 5th byte C3 C8 C13 C18 C23 C28 C33 * specifies 4th column data (5th) : rewritten into CGRAM address 00H LSB MSB B0 B1 B2 B3 Β4 B5 B6 B7 * 6th byte C9 C14 C19 C24 C29 C34 specifies 5th column data C4 (6th) : rewritten into CGRAM address 00H

To specify character pattern data continuously to the next address, specify only character pattern data as follows.

The addresses of CGRAM are automatically incremented. Specification of an address is therefore unnecessary.

The 2nd to 6th byte (character pattern data) are regarded as one data item, so 300 ns is sufficient for t_{DOFF} time between bytes.

2nd byte (7th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data : rewritten into CGRAM address 01H
6th byte (11th)	LSB MSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * : LSB MSB MSB MSB MSB MSB MSB B0 B1 B2 B3 B4 B5 B6 B7	specifies 5th column data : rewritten into CGRAM address 01H
2nd byte (12th)	C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data : rewritten into CGRAM address 02H
6th byte (16th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * :	specifies 5th column data : rewritten into CGRAM address 02H
2nd byte (77th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data : rewritten into CGRAM address 0FH
6th byte (81th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * : LSB B0 B1 B2 B3 B4 B5 B6 B7	specifies 5th column data : rewritten into CGRAM address 0FH
2nd byte (82th)	C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data : rewritten into CGRAM address 10H
6th byte (86th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * :	specifies 5th column data : rewritten into CGRAM address 10H
2nd byte (157th)	B0 B1 B2 B3 B4 B5 B6 B7 C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data : rewritten into CGRAM address 1FH
6th byte (161th)	LSB MSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * : LSB B0 B1 B2 B3 B4 B5 B6 B7	specifies 5th column data : rewritten into CGRAM address 1FH
2nd byte (162th)	C0 C5 C10 C15 C20 C25 C30 * :	specifies 1st column data (CGRAM address 00H is rewritten)
6th byte (167th)	LSB B0 B1 B2 B3 B4 B5 B6 B7 C4 C9 C14 C19 C24 C29 C34 * :	specifies 5th column data (CGRAM address 00H is rewritten)

X0 (LSB) to X3 (MSB): CGRAM addresses (4 bits: 16 characters) Note: A total of 32 characters for the two specifications. C0 (LSB) to C34 (MSB): Character pattern data (35 bits: 35 outputs per digit)

Positional relationship between the output area of CGROM and that of CGRAM

	C0 C5 C10 C15 C20 C25 C30	C1 C6 C11 C16 C21 C26 C31	C2 C7 C12 C17 C22 C27 C32	C3 C8 C13 C18 C23 C28 C33	C4 C9 C14 C19 C24 C29 C34	
byte (1st column) byte (2nd column)					<u> </u>	area that corresponds to 6th byte (5th column) area that corresponds to 5th byte (4th column) area that corresponds to 4th byte (3rd column)

area that corresponds to 2nd byte (1st column) area that corresponds to 3rd byte (2nd column)

Note: CGROM (Character Generator ROM) has an 8-bit address to generate 5×7 dot matrix character patterns.

The capacity is 224×35×8 bits, which can store 224 types of character patterns.

2 types of general-purpose code are availble (see ROM CODE list) and custom codes are provided on customer's request.

[CGROM addresses and set CGRAM addresses]

Command	HEX	к0	V 4	К2	кз	CGROM	Command	HEX	к0	V 4	К2	K 2	CGROM
No.	ПЕХ	NU	NI	n 2	NЭ	address	No.	ПЕЛ	NU	N I	n 2	NЭ	address
	00	0	0	0	0	RAM00(0000000B)		10	0	0	0	0	RAM10(00010000B)
	01	1	0	0	0	RAM01(0000001B)		11	1	0	0	0	RAM11(00010001B)
	02	0	1	0	0	RAM02(00000010B)		12	0	1	0	0	RAM12(00010010B)
	03	1	1	0	0	RAM03(00000011B)		13	1	1	0	0	RAM13(00010011B)
	04	0	0	1	0	RAM04(00000100B)		14	0	0	1	0	RAM14(00010100B)
	05	1	0	1	0	RAM05(00000101B)		15	1	0	1	0	RAM15(00010101B)
	06	0	1	1	0	RAM06(00000110B)		16	0	1	1	0	RAM16(00010110B)
2	07	1	1	1	0	RAM07(00000111B)	4	17	1	1	1	0	RAM17(00010011B)
2	08	0	0	0	1	RAM08(00001000B)	4	18	0	0	0	1	RAM18(00011000B)
	09	1	0	0	1	RAM09(00001001B)		19	1	0	0	1	RAM19(00011001B)
	0A	0	1	0	1	RAM0A(00001010B)		1A	0	1	0	1	RAM1A(00011010B)
	0B	1	1	0	1	RAM0B(00001011B)		1B	1	1	0	1	RAM1B(00011011B)
	00	0	0	1	1	RAM0C(00001100B)		10	0	0	1	1	RAM1C(00011100B)
	0D	1	0	1	1	RAM0D(00001101B)		1D	1	0	1	1	RAM1D(00011101B)
	0E	0	1	1	1	RAM0E(00001110B)		1E	0	1	1	1	RAM1E(00011110B)
	0F	1	1	1	1	RAM0F(00001111B)		1F	1	1	1	1	RAM1F(00011111B)

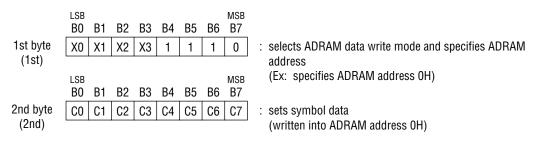
Refer to ROMCODE table

7. ADRAM data write

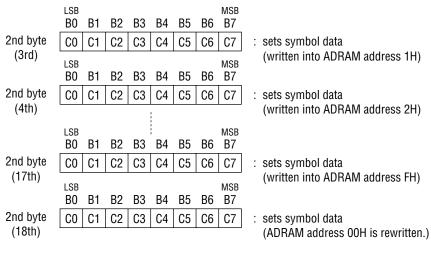
(specifies address of ADRAM and writes symbol data)

ADRAM (Additional Data RAM) has a 4-bit address to store symbol data. Symbol data specified by ADRAM is directly output without CGROM and CGRAM. The capacity is 8×16 bits, which can store 8 types of symbol patterns for each digit. The terminal to which the contents of ADRAM are output can be used as a cursor.

[Command format]



To specify symbol data continuously to the next address, specify only symbol data as follows. The address of ADRAM is automatically incremented. Specification of addresses is therefore unnecessary.



X0 (LSB) to X3 (MSB): ADRAM addresses (4 bits: 16 characters) C0 (LSB) to C7 (MSB): Symbol data (8-symbol data per digit)

HEX	D0	D1	D2	D3	COM position	HEX	D0	D1	D2	D3	COM position
0	0	0	0	0	COM1	8	0	0	0	1	COM9
1	1	0	0	0	COM2	9	1	0	0	1	COM10
2	0	1	0	0	COM3	А	0	1	0	1	COM11
3	1	1	1	0	COM4	В	1	1	0	1	COM12
4	0	0	1	0	COM5	С	0	0	1	1	COM13
5	1	0	1	0	COM6	D	1	0	1	1	COM14
6	0	1	1	0	COM7	Е	0	1	1	1	COM15
7	1	1	1	0	COM8	F	1	1	1	1	COM16

[COM positions and ADRAM addresses]

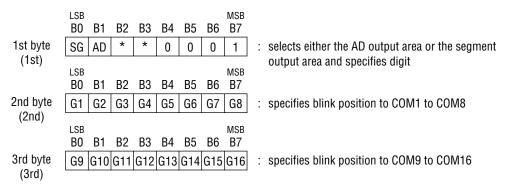
8. Display blink position set

(sets the blink position for the SEG area or AD area in COMn.

Display blink position can be set separately for the SEG area and AD area. In this case, select by command in which COMn the SEG area or AD area is made blink.

The blink disabled state is entered for this setting when power is turned on or when a **RESET** signal is input. The display blink cycle is determined by the frequency to be input to the BLINK pin.

[Command format]



The 2nd and 3rd bytes (COM1 to COM16 position specification) are regarded as one data item, so 300 ns is sufficient for t_{DOFF} time between bytes.

SG: Specifies SEG area AD: Specifies AD area Gn: Specifies blinks [SEG and AD display and set data]

SG/AD	Gn	SEG and AD display	
0	0	Does not blink (current state)	(The state when power is applied or when RESET is input)
0	1	Does not bilnk (current state)	
1	0	Specified positions do not blink	
1	1	Specified positions blink	

Note: If both SG and AD are set to "1" by command, both the SEG area and the AD area are specified.

9. DCRAM address shift (Shifts SEG output left or right.)

 ${\rm DCRAM}$ address shift shifts SEG output 1 digit to the left or right using 1 bit data. AD output cannot be shifted.

[Command format]

	lsb B0	B1	B2	B3	B4	B5	B6	msb B7	
1st byte	SG	*	*	*	1	0	0	1	

: selects DCRAM address shift and sets shift value (left, right)

S: Specifies the direction of shift

[Set data and shift direction of display]

S	Shift direction of display
0	Shift to left
1	Shift to right

[DCRAM address shift and COM positions]

Command No.	HEX	к0	К1	К2	кз	COM position	Command No.	HEX	ко	К1	К2	кз	COM position
	00	0	0	0	0	COM2		20	0	0	0	0	
	01	1	0	0	0	COM3		21	1	0	0	0	
1	 			 			3	1 1 1 1			 		
	0E	0	1	1	1	COM16		2E	0	1	1	1	
	0F	1	1	1	1			2F	1	1	1	1	
	10	0	0	0	0			30	0	0	0	0	
	11	1	0	0	0			31	1	0	0	0	
2	 			 			4	 			 		
	1E	0	1	1	1			3E	0	1	1	1	
	1F	1	1	1	1			3F	1	1	1	1	COM1

When S=0 (shift to left) is performed from the initial state.

When S=1 (shift to right) is performed from the initial state.

Command No.	HEX	к0	К1	К2	КЗ	COM position	Command No.	HEX	к0	К1	К2	КЗ	COM position
	00	0	0	0	0			20	0	0	0	0	
	01	1	0	0	0	COM1		21	1	0	0	0	
1	1			 			3	1			 		
	0E	0	1	1	1	COM14		2E	0	1	1	1	
	0F	1	1	1	1	COM15		2F	1	1	1	1	
	10	0	0	0	0	COM16		30	0	0	0	0	
	11	1	0	0	0			31	1	0	0	0	
2	1			 			4				1		
	1E	0	1	1	1			3E	0	1	1	1	
	1F	1	1	1	1			3F	1	1	1	1	

A. DCRAM address reset

(returns display status to initial setting status)

The DCRAM address reset returns the status where a DCRAM address shift is executed to initial status.

[Command format]

	LSB							MSB	
	B0	B1	B2	B3	B4	B5	B6	B7	
1st byte	*	*	*	*	0	1	0	1	: selects DCRAM address reset

Relation between the DCRAM address shifts and the COM outputs

Initial status or the status where display address reset executed (DCRAM address is 00H)

COM output	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
DCRAM address (HEX)	00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F

When left shift is executed in the initial status

COM output	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
DCRAM address (HEX)	3F	00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E

When right shift is executed in the initial status

COM output	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
DCRAM address (HEX)	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F	10

B. General output port set

(specifies the general output port status)

The general output port is an output for 4-bit static operation.

It is used to control other I/O devices and turn on LED.

When at the "High" level, this output becomes the V_{DD} voltage, and when at the "Low" level, it becomes the ground potential. Therefore, the fluorescent display tube cannot be driven.

[Command format]

	lsb B0	B1	B2	B3	B4	B5	B6	MSB B7	
1st byte	P1	P2	P3	P4	1	1	0	1	

: selects a general output port and specifies the output status

P1-P4: general output port

[Set data and set state of general output port]

Pn	Display state of general output port	
0	Sets to the output to Low	(The state when power is applied or when $\overrightarrow{\text{RESET}}$ is input.)
1	Sets to the output to High	

C. Display duty set

(writes display duty value to duty cycle register)

Display duty adjusts contrast in 16 stages using 4-bit data.

When power is turned on or when the RESET signal is input, the duty cycle register value is "0". Always execute this instruction before turning the display on, then set a desired duty value.

[Command format]

	lsb B0	B1	B2	B3	B4	B5	B6	MSB B7	
1st byte	D0	D1	D2	D3	0	0	1	1	: selects display duty set mode and sets duty value

D0 (LSB) to D3 (MSB): display duty data (4 bits: 16 stages)

HEX	D3	D2	D1	D0	COM duty	HEX	D3	D2	D1	D0	COM duty
* 0	0	0	0	0	0/16	8	1	0	0	0	8/16
1	0	0	0	1	1/16	9	1	0	0	1	9/16
2	0	0	1	0	2/16	А	1	0	1	0	10/16
3	0	0	1	1	3/16	В	1	0	1	1	11/16
4	0	1	0	0	4/16	С	1	1	0	0	12/16
5	0	1	0	1	5/16	D	1	1	0	1	13/16
6	0	1	1	0	6/16	Е	1	1	1	0	14/16
7	0	1	1	1	7/16	F	1	1	1	1	15/16

[Relation between setup data and controlled COM duty]

* The state when powered on or when **RESET** signal inputs.

D. Number of digits set

(writes the number of display digits to the display digit register)

The number of digits set can display a maximum of 16 digits using 4-bit data. When power is turned on or when a RESET signal is input, the number of digit register value is "0". Always execute this instruction to change the number of digits before turning the dispaly on.

[Command format]

	LSB R0	B1	B2	B3	R4	B5	B6	MSB B7		
1st byte									:	S

selects the number of digit set mode and specifies the number of digit value

K0 (LSB) to K3 (MSB): number of digit data (4 bits: 16 digits)

HEX	кз	К2	К1	к0	Number of digits of COM	HEX	КЗ	К2	К1	ко	Number of digits of COM
0	0	0	0	0	COM1-16	8	1	0	0	0	COM1-8
1	0	0	0	1	COM1-1	9	1	0	0	1	COM1-9
2	0	0	1	0	COM1-2	A	1	0	1	0	COM1-10
3	0	0	1	1	COM1-3	В	1	0	1	1	COM1-11
4	0	1	0	0	COM1-4	С	1	1	0	0	COM1-12
5	0	1	0	1	COM1-5	D	1	1	0	1	COM1-13
6	0	1	1	0	COM1-6	E	1	1	1	0	COM1-14
7	0	1	1	1	COM1-7	F	1	1	1	1	COM1-15

[Relation between setup data and controlled COM]

E. All display lights ON/OFF set (turns all dispaly lights ON or OFF)

All display lights ON is used primarily for display testing. All display lights OFF is primarily used to prevent malfunction when power is turned on.

[Command format]

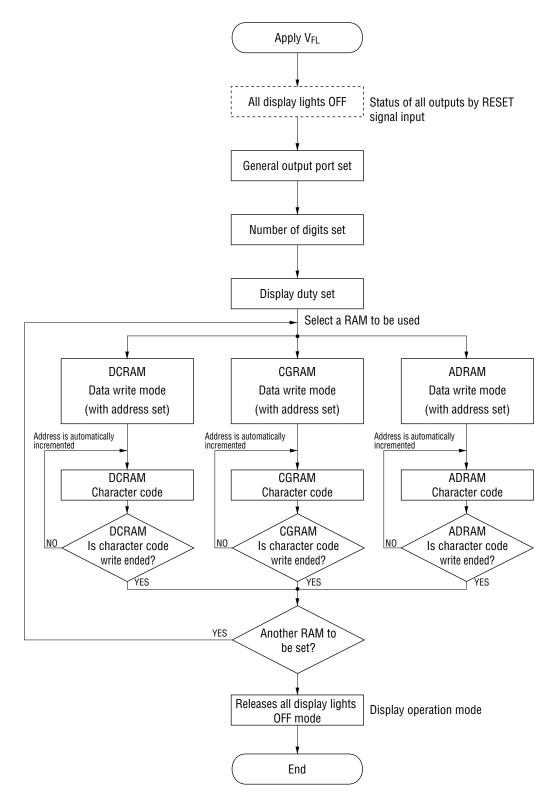
	lsb B0	B1	B2	B3	B4	B5	B6	msb B7	
1st byte	L	Η	*	*	0	1	1	1	

: selects all display lights ON or OFF mode and sets all lights ON or OFF value

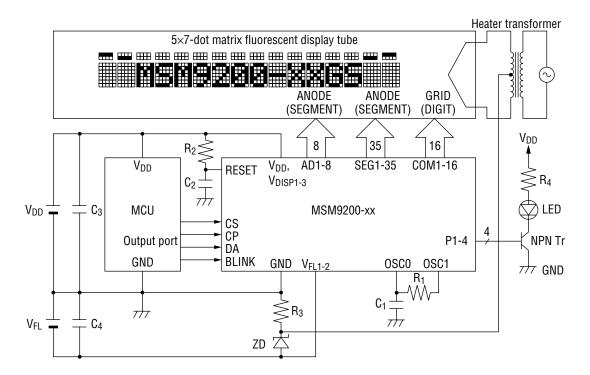
[Set data and display state of SEG and AD]

L	Н	Display state of SEG and AD	
0	0	All outputs maintain current states	
1	0	Sets all outputs to Low	(The state when power is applied or when RESET is input.)
0	1	Sets all outputs to High	
1	1	Sets all outputs to High	(All lights ON mode has priority.)

Initial Setting Flowchart



APPLICATION CIRCUIT

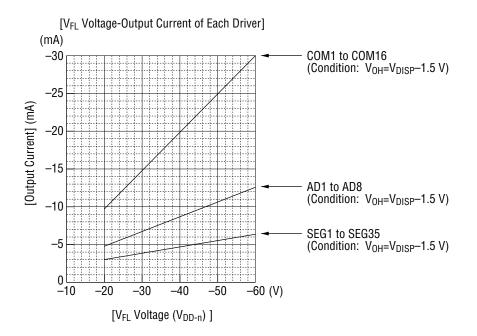


- Notes: 1. The V_{DD} value depends on the power supply voltage of the microcontroller used. Adjust the values of the constants R₁, R₂, R₄, C₁, and C₂ to the power supply voltage used.
 - 2. The V_{FL} value depends on the fluorescent display tube used. Adjust the values of the constants R_3 and ZD to the power supply voltage used.

Reference data

The figure below shows the relationship between the V_{FL} voltage and the output current of each driver.

Take care that the total power consumtion to be used does not exceed the power dissipation.



MSM9200-01 ROM Code

00000000B (00H) to 00011111B (1FH) are the CGRAM addresses.

MSB																
LSB	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111
0000	RAM00	RAM10														
0001	RAM01	RAM11														
0010	RAM02	RAM12														
0011	RAM03	RAM13														
0100	RAM04	RAM14														
0101	RAM05	RAM15														
0110	RAM06	RAM16														
0111	RAM07	RAM17														
1000	RAM08	RAM18														
1001	RAM09	RAM19														
1010	RAM0A	RAM1A														
1011	RAMOB	RAM1B														
1100	RAMOC	RAM1C														
1101	RAMOD	RAM1D														
1101	RAMOE	RAM1E														
1111	RAMOF	RAM1F														

MSM9200-02 ROM Code

00000000B (00H) to 00011111B (1FH) are the CGRAM addresses.

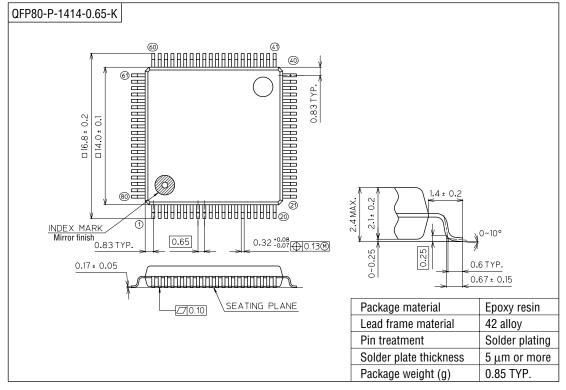
MSB																
LSB	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111
0000	RAM00	RAM10														
0001	RAM01	RAM11														
0010	RAM02	RAM12														
0011	RAM03	RAM13														
0100	RAM04	RAM14														
0101	RAM05	RAM15														
0110	RAM06	RAM16														
0111	RAM07	RAM17														
1000	RAM08	RAM18														
1001	RAM09	RAM19														
1010	RAM0A	RAM1A														
1011	RAMOB	RAM1B														
1100	RAMOC	RAM1C														
1101	RAMOD	RAM1D														
1101	RAM0E	RAM1E														
1111	RAMOF	RAM1F														

Digit Output Timing (for 16-digit display, at a duty of 15/16)

T=8/ f ₀ ;	 Frame cycle Display timing Blank timing 	t ₁ =1024T t ₂ =60T t ₃ =4T	ms when f s when f _{osc} when f _{osc} =	=2.0 MHz	<u>z)</u>		Р
COM1 COM2 COM3 COM4						V _{FL}	
COM5 COM6	 						
COM7 COM8 COM9						 	
COM10 COM11						 	
COM12 COM13 COM14							
COM15 COM16					ſ		
AD1-8 SEG1-35	 <u> </u>		 			 V _{DISI} ──V _{FL}	Ρ

PACKAGE DIMENSIONS

(Unit : mm)



Notes for Mounting the Surface Mount Type Package

The SOP, QFP, TSOP, SOJ, QFJ (PLCC), SHP and BGA are surface mount type packages, which are very susceptible to heat in reflow mounting and humidity absorbed in storage.

Therefore, before you perform reflow mounting, contact Oki's responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).